

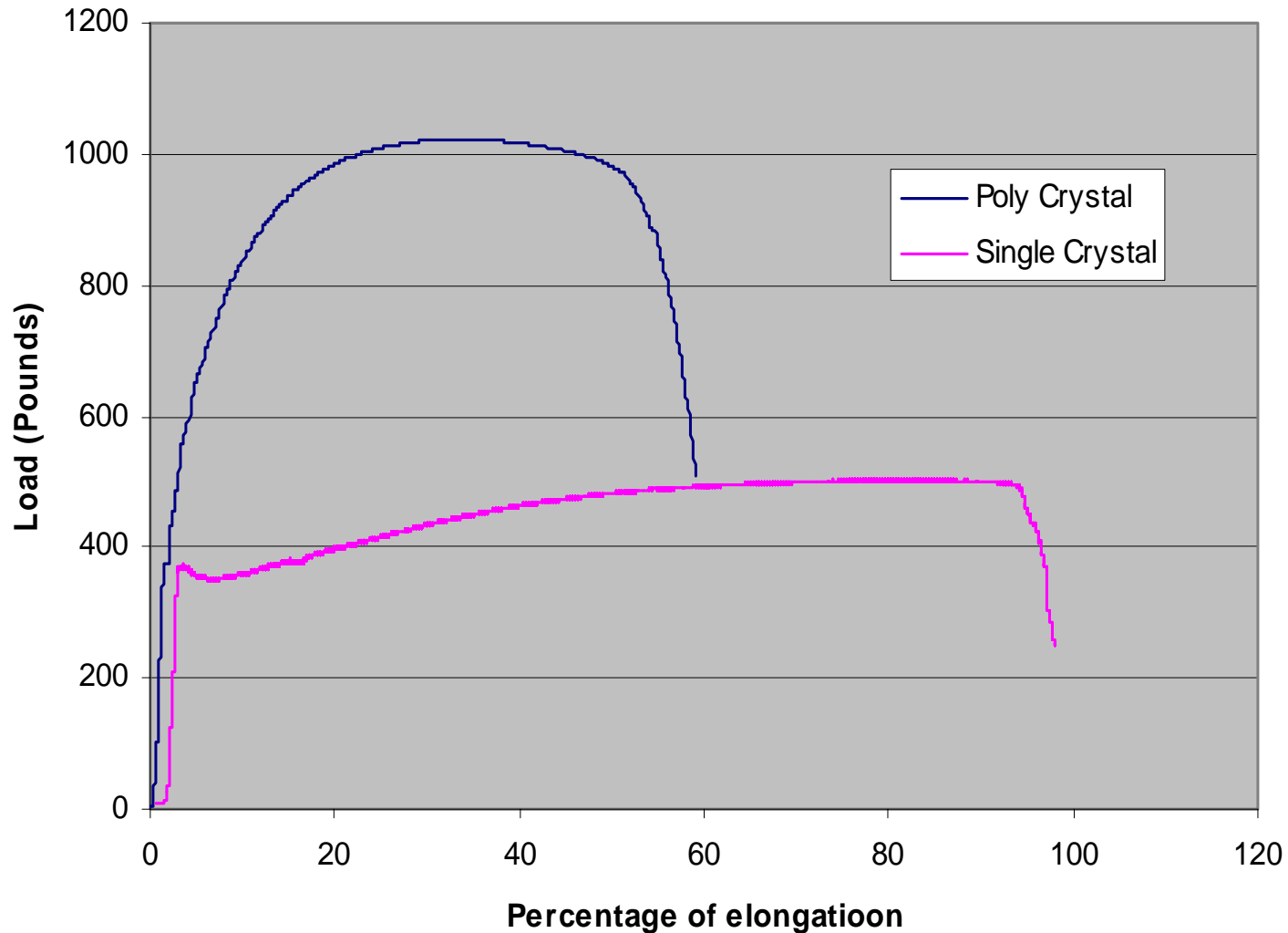
Preliminary Results from Large Grain and Single Crystal Niobium cavities

P. Kneisel, G. Ciovati, G.R.Myneni, Jlab
and J. Sekutowicz, DESY

TESLA Collaboration Meeting March 30-April 1, 2005

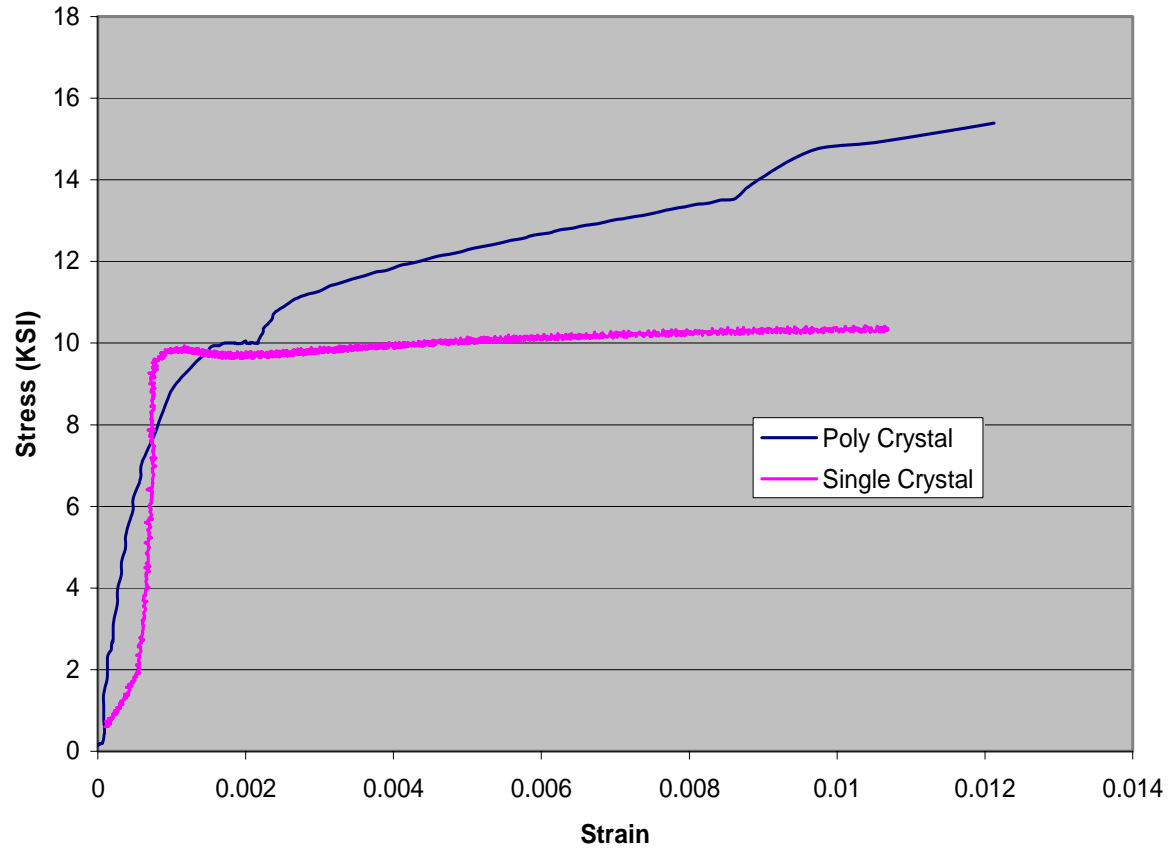
Single Crystal Niobium(1)

Comparison of Single and Poly Crystal RRR niobium



Single Crystal Niobium (2)

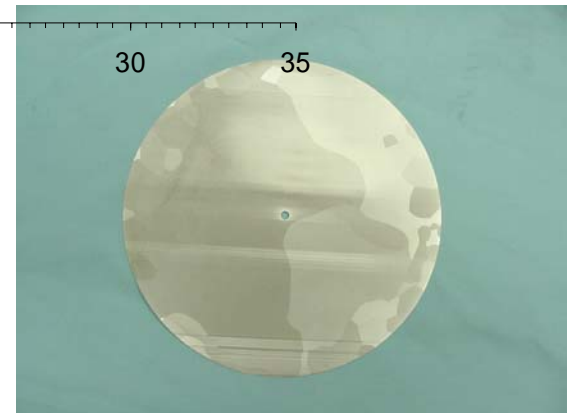
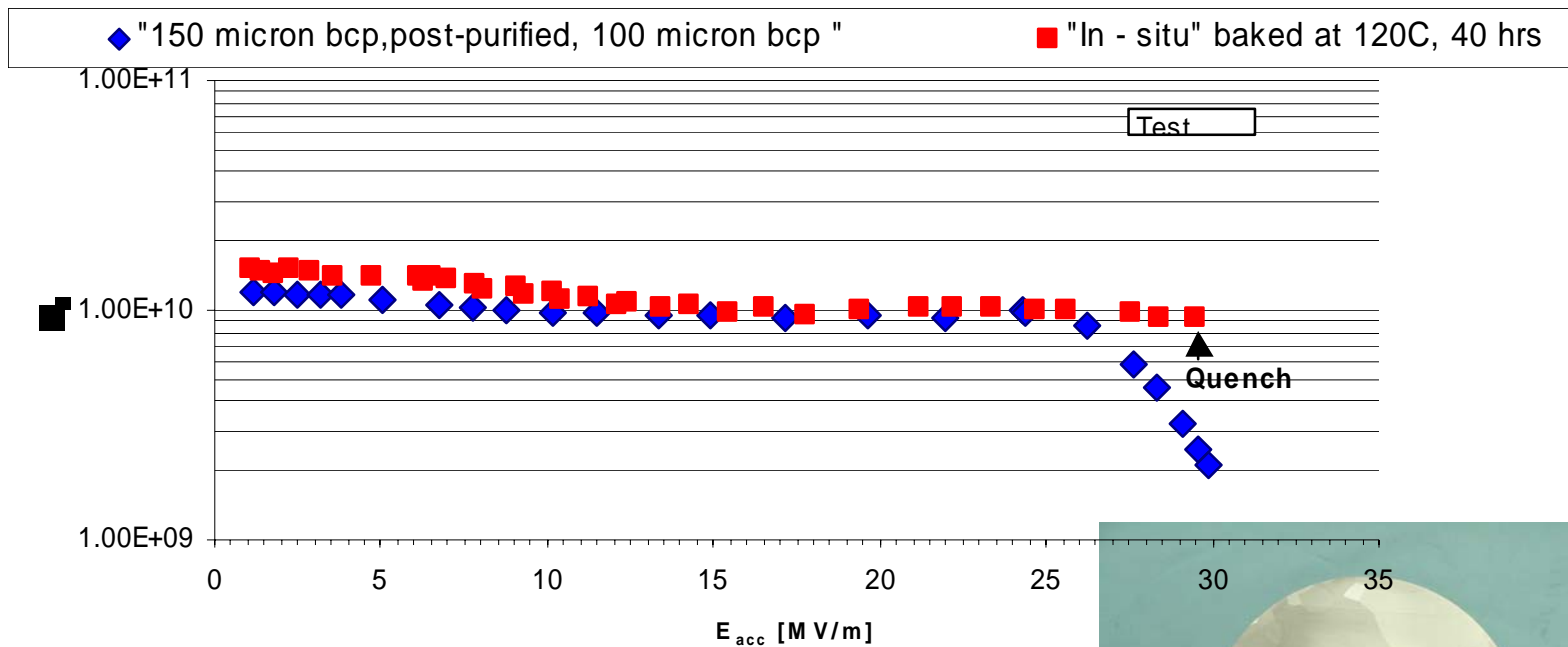
Comparison of Single Crystal and Polycrystal RRR niobium



Large Grain Niobium (1.5 GHz)

Ingot "B"

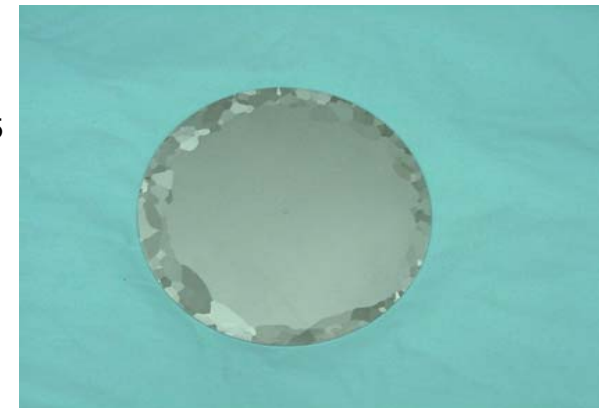
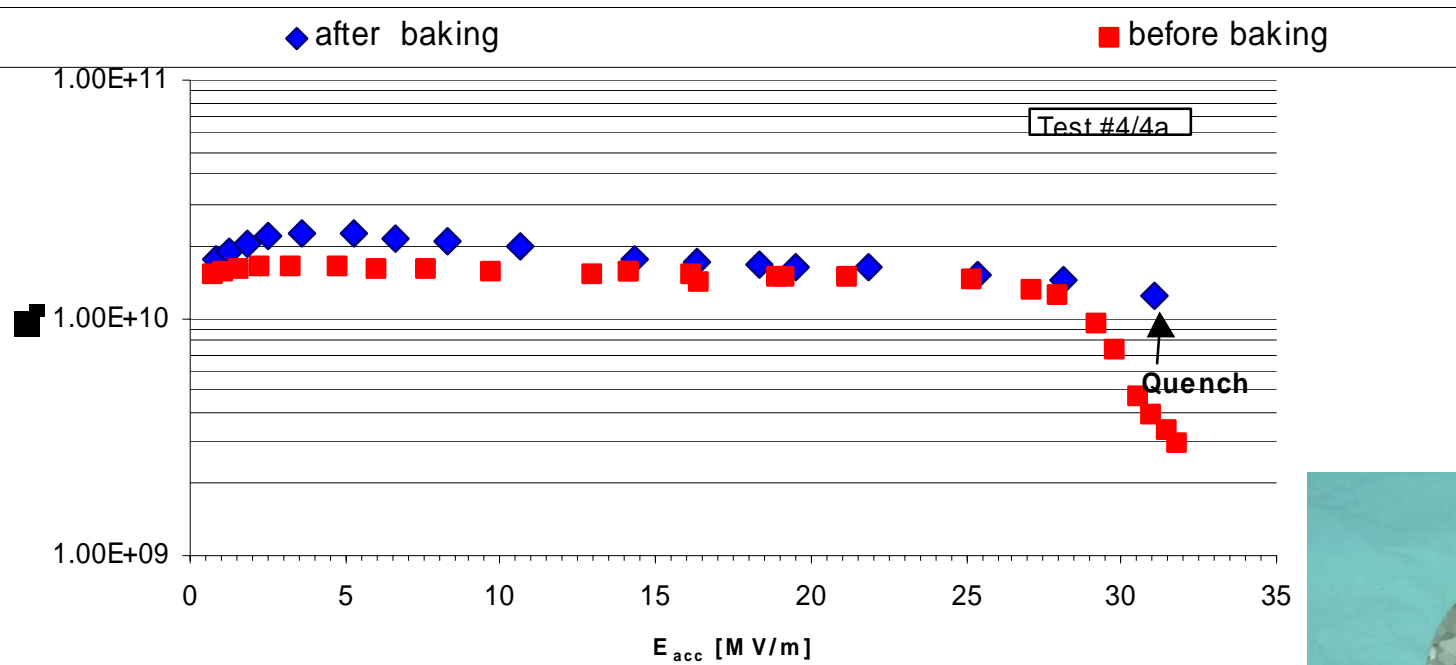
HG Single Cell Cavity - "Single Crystal" -B
 Q_0 vs. E_{acc}



Large Grain Niobium (1.5 GHz)

Ingot "A"

HG Single Cell Cavity - "Single Crystal" -A
 Q_0 vs. E_{acc}



Single Crystal Niobium Cavity (1)

Discs from Ingot



Cavity

$$E_{\text{peak}}/E_{\text{acc}} = 1.674$$

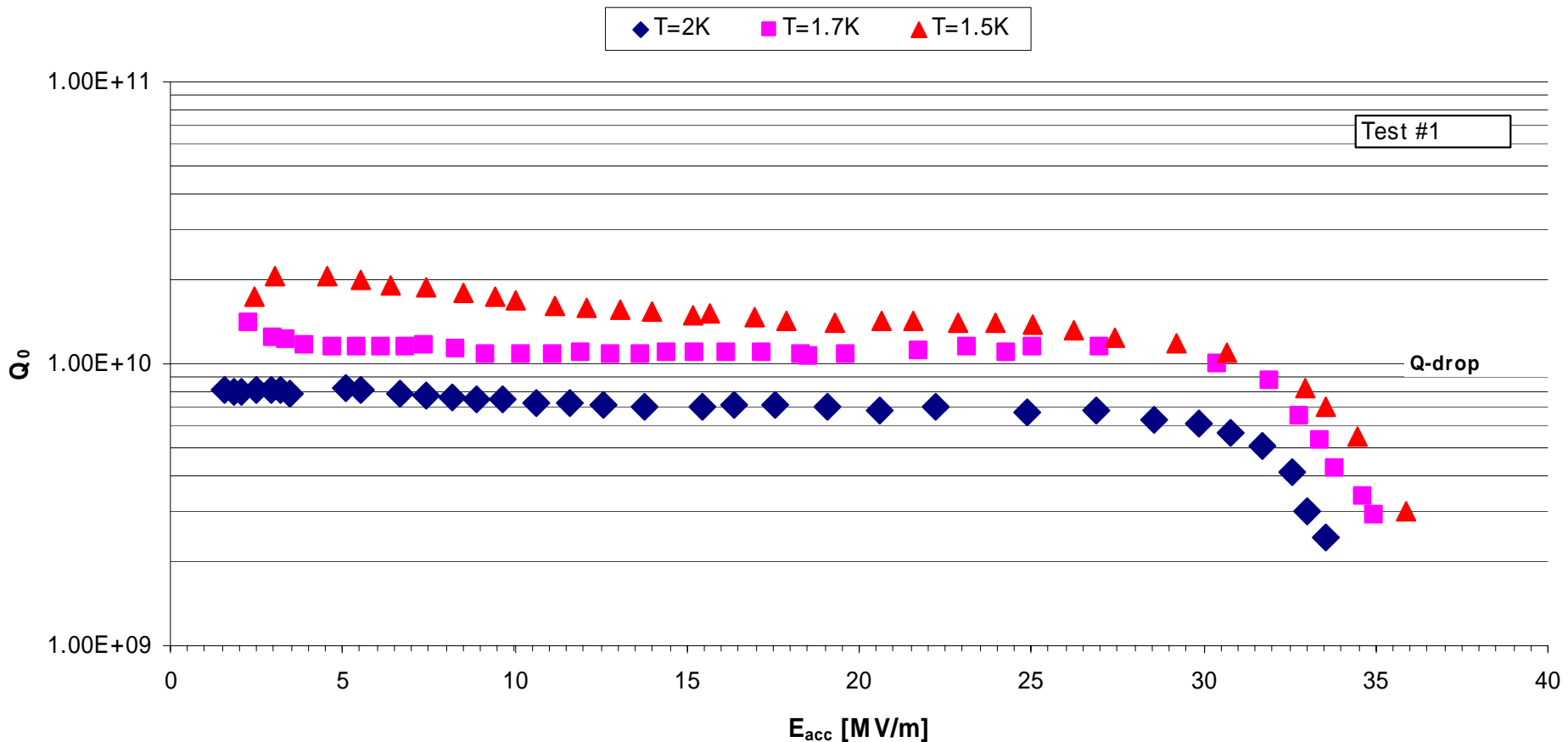
$$H_{\text{peak}}/E_{\text{acc}} = 4.286 \text{ mT/MV/m}$$



Single Crystal Niobium Cavity (2)

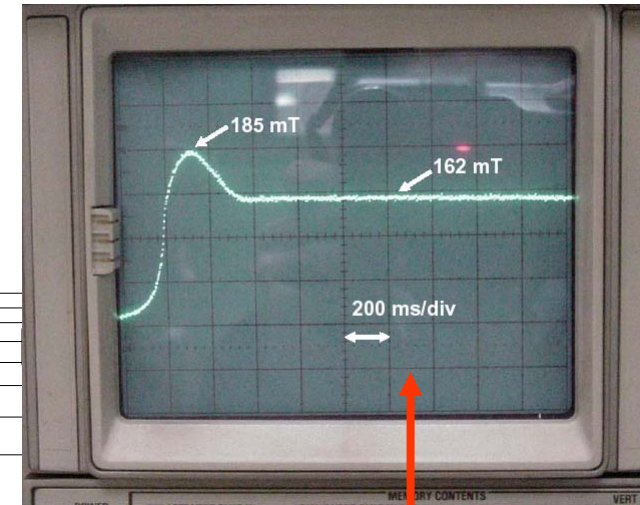
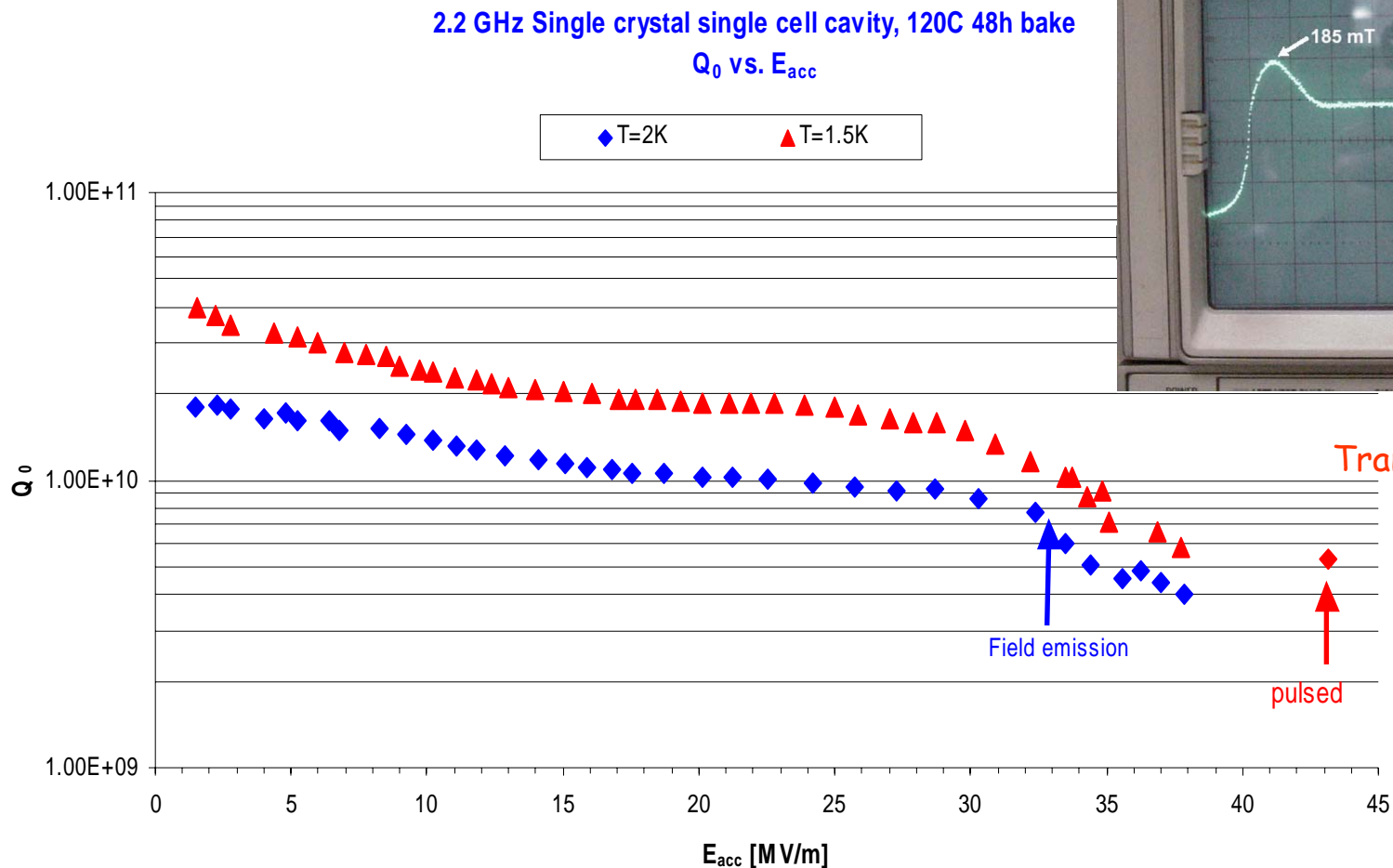
Test #1a: Treatment 100 μm BCP, 800C hydrogen degassing, 100 μm BCP, high pressure rinsing for 30 min

2.2 GHz Single crystal single cell cavity
 Q_0 vs. E_{acc}



Single Crystal Niobium Cavity (3)

Test #1b: Treatment 100 μm BCP, 800C hydrogen degassing, 100 μm BCP, high pressure rinsing, "in situ" baked at 120C for 48 hrs

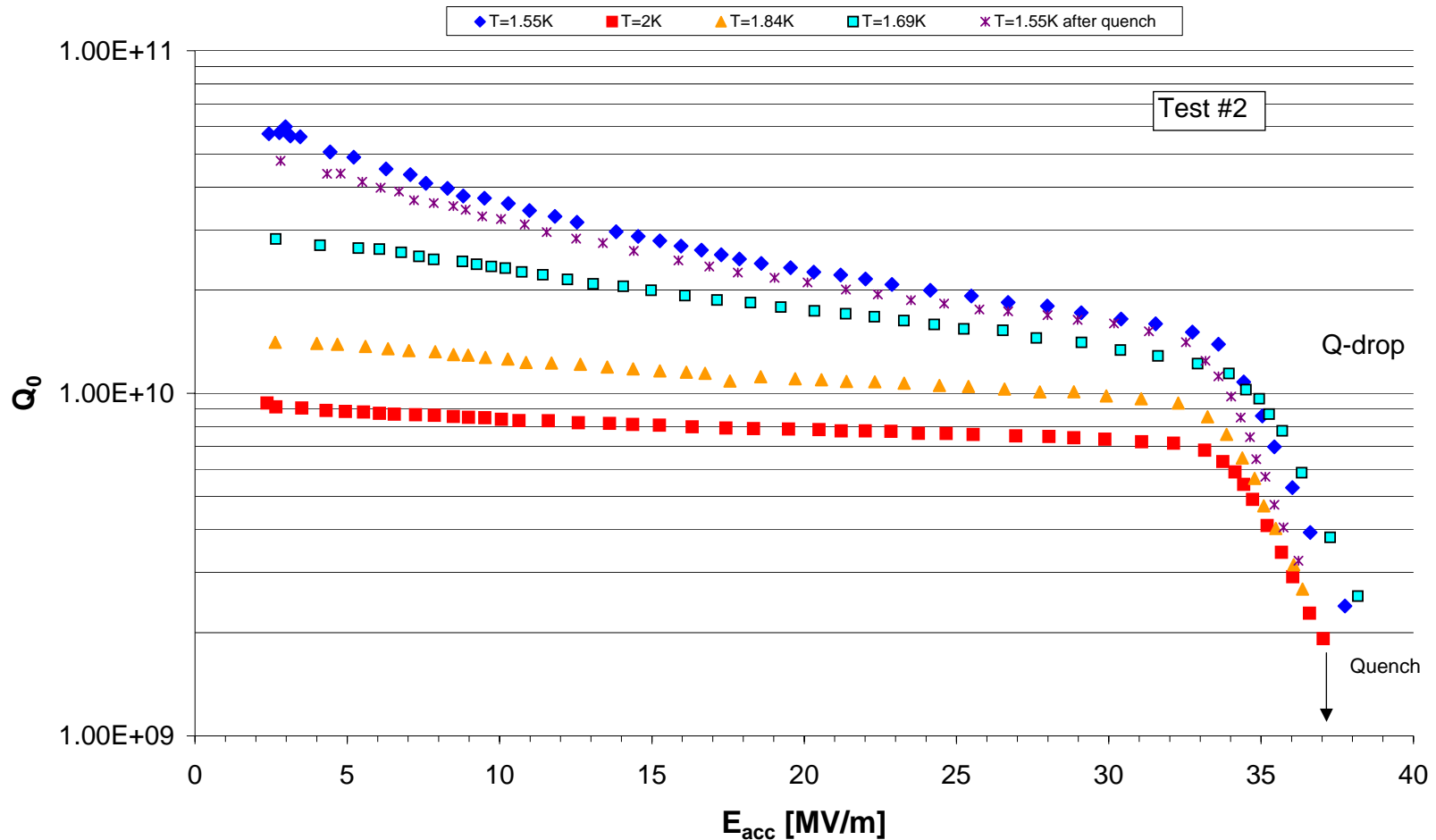


Single Crystal Niobium Cavity (4)

Test #2 (before baking)

2.2 GHz Single crystal single cell cavity after post-purification, 70 μ m BCP 1:1:1, 30min HPR

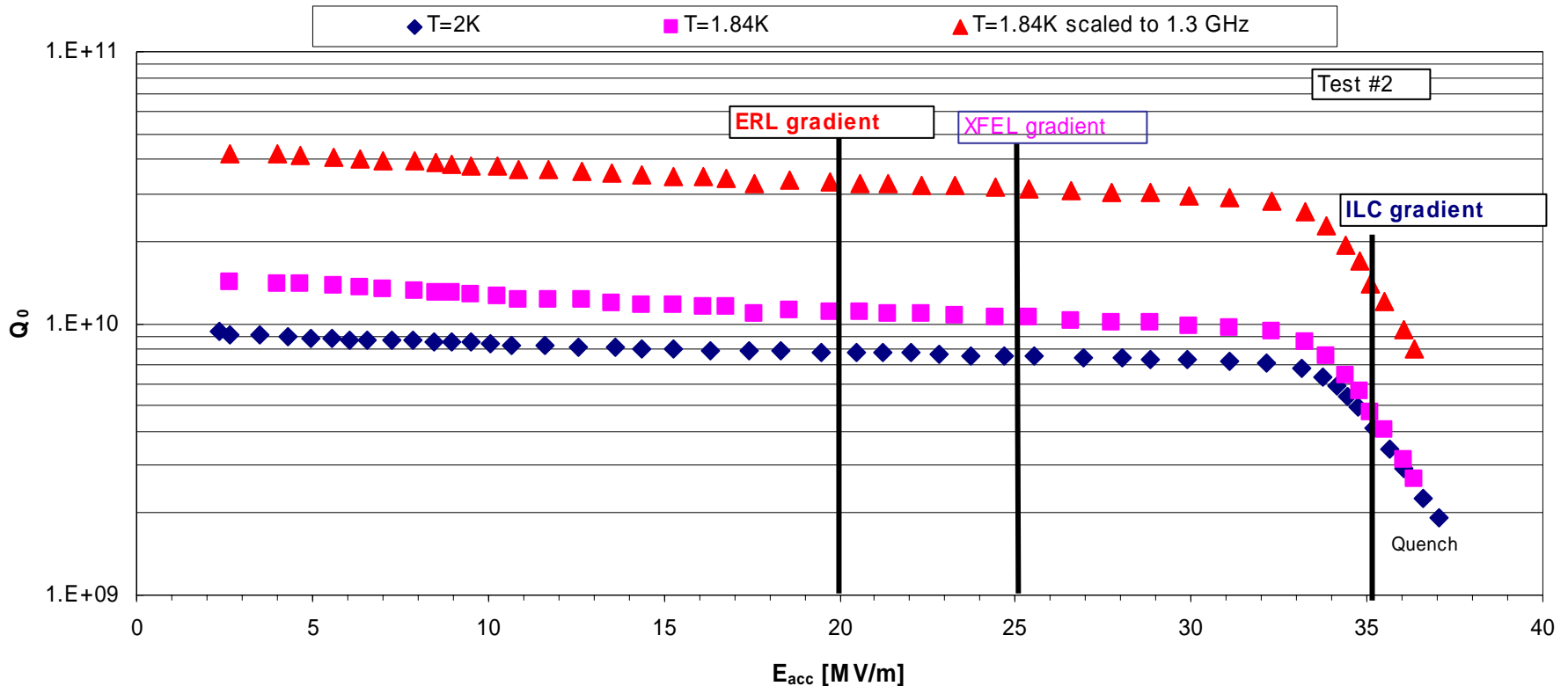
Q_0 vs. E_{acc}



Single Crystal Niobium Cavity (5)

Test #2: post-purification heat treatment at 1250 C for 10 hrs, 100 μm BCP, high pressure rinsing

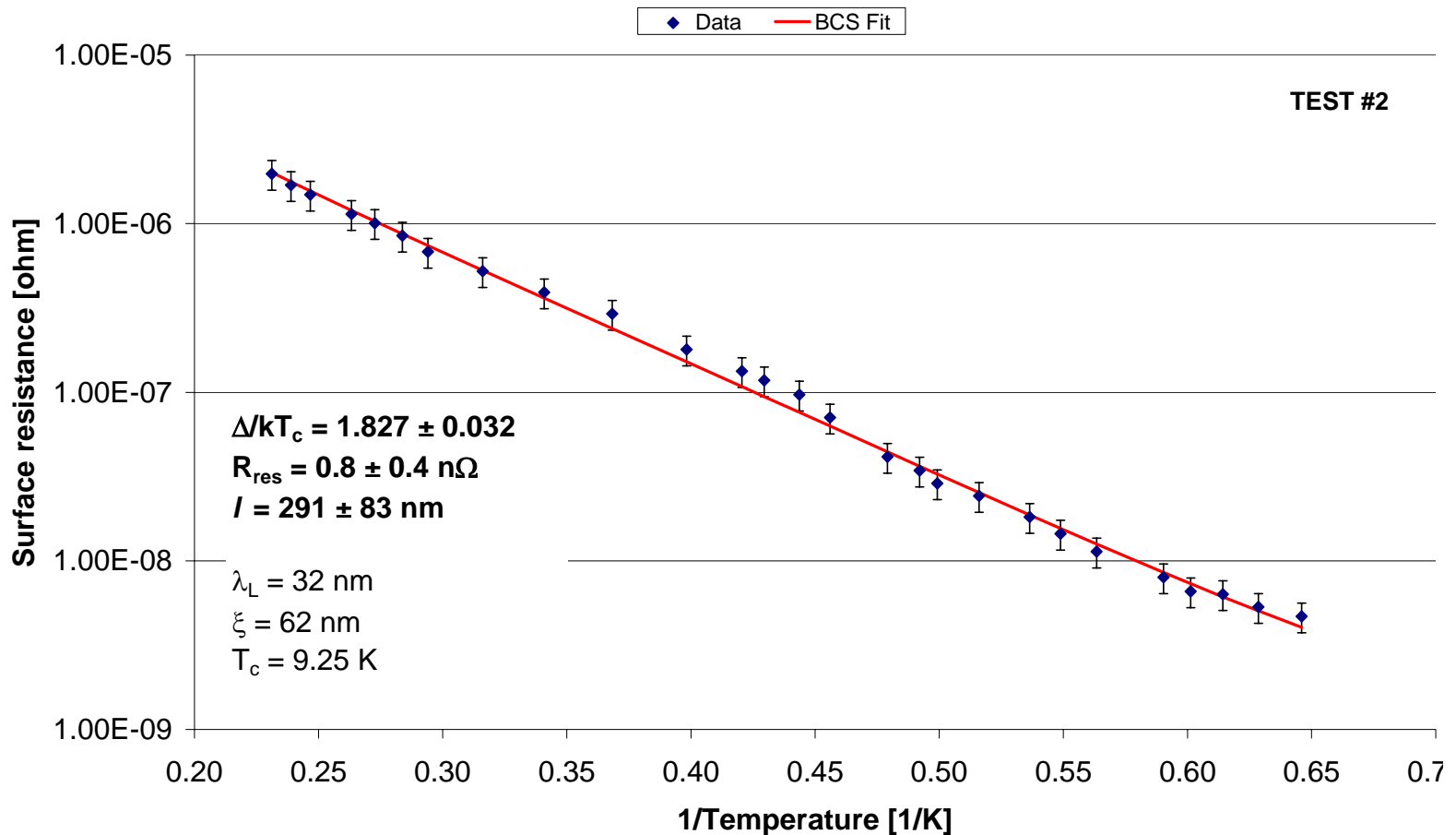
2.2 GHz Single crystal single cell cavity after postpurification
 Q_0 vs. E_{acc}



Single Crystal Niobium Cavity (6)

Test #2: T-dependence (before baking)

2.2 GHz Single crystal single cell cavity after post-purification, 70mm BCP 1:1:1,
30min HPR

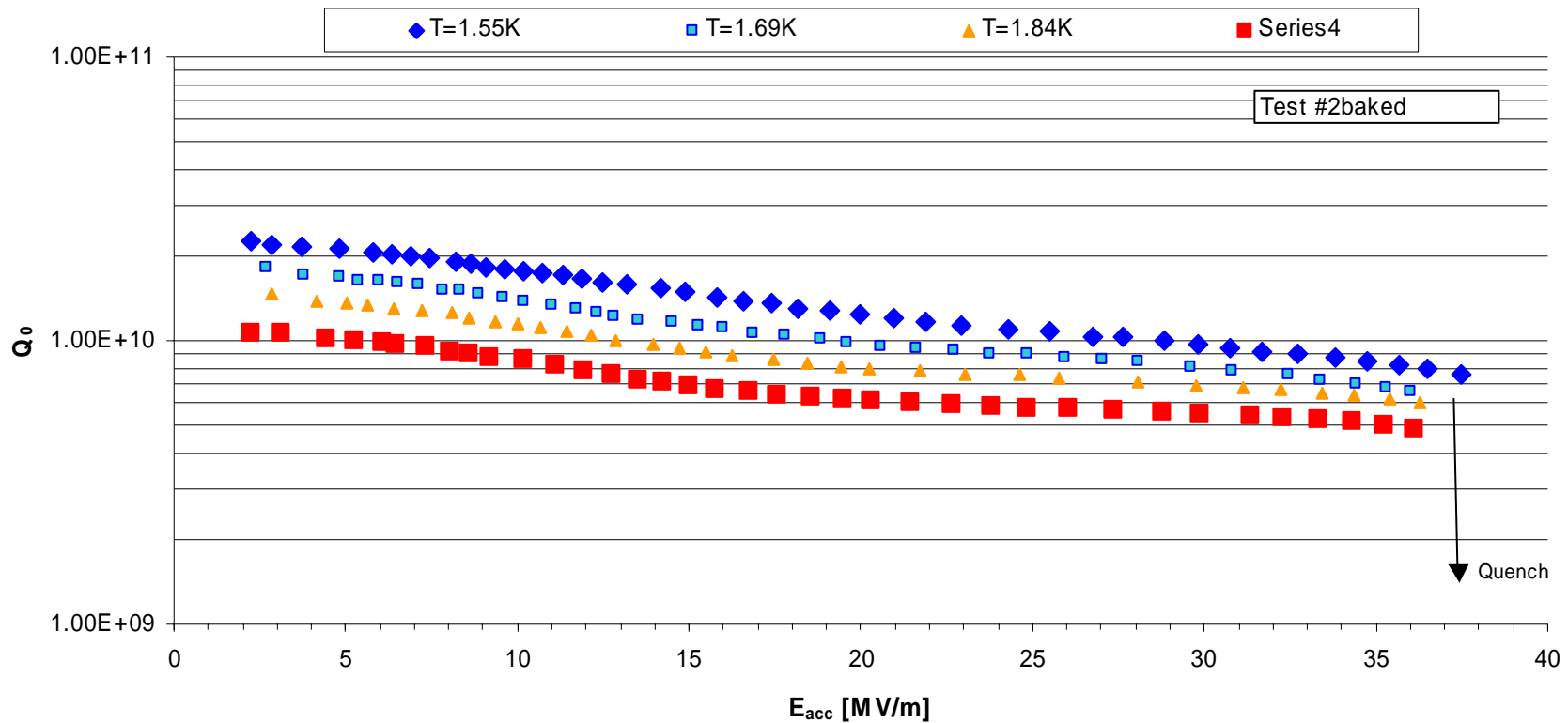


Single Crystal Niobium Cavity (7)

Test #2: after baking at 120C, ~44 hrs

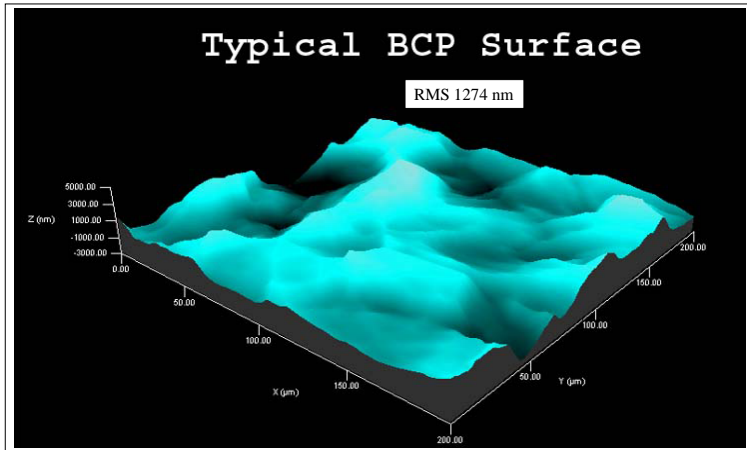
2.2 GHz Single crystal single cell cavity after 120C 45h bake

Q_0 vs. E_{acc}

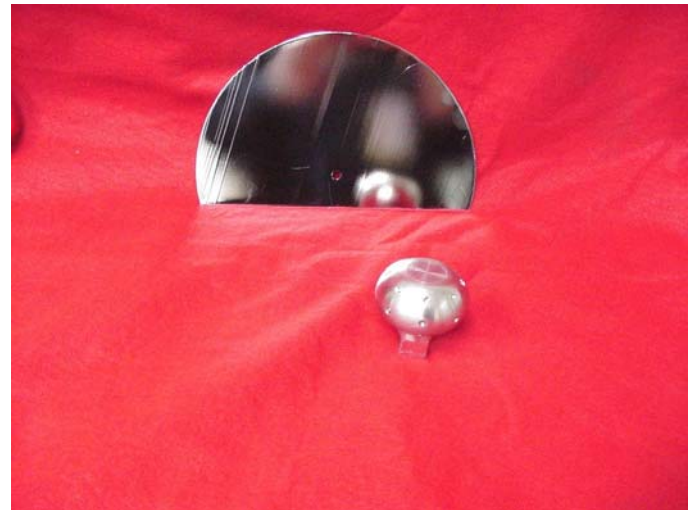
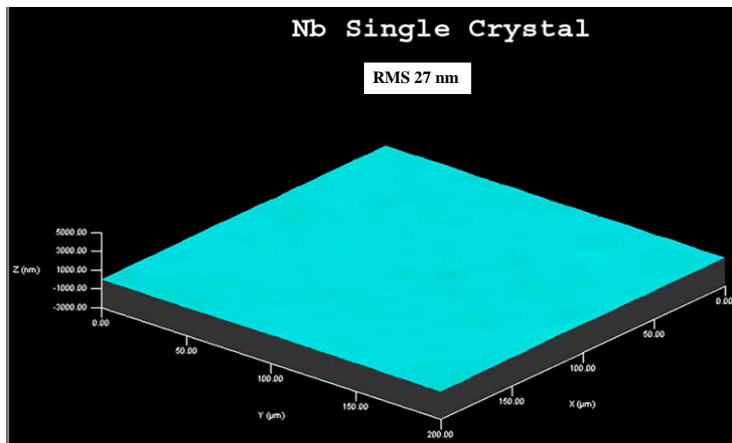


Single Crystal BCP

Provides very smooth surfaces as measured by A.Wu, Jlab



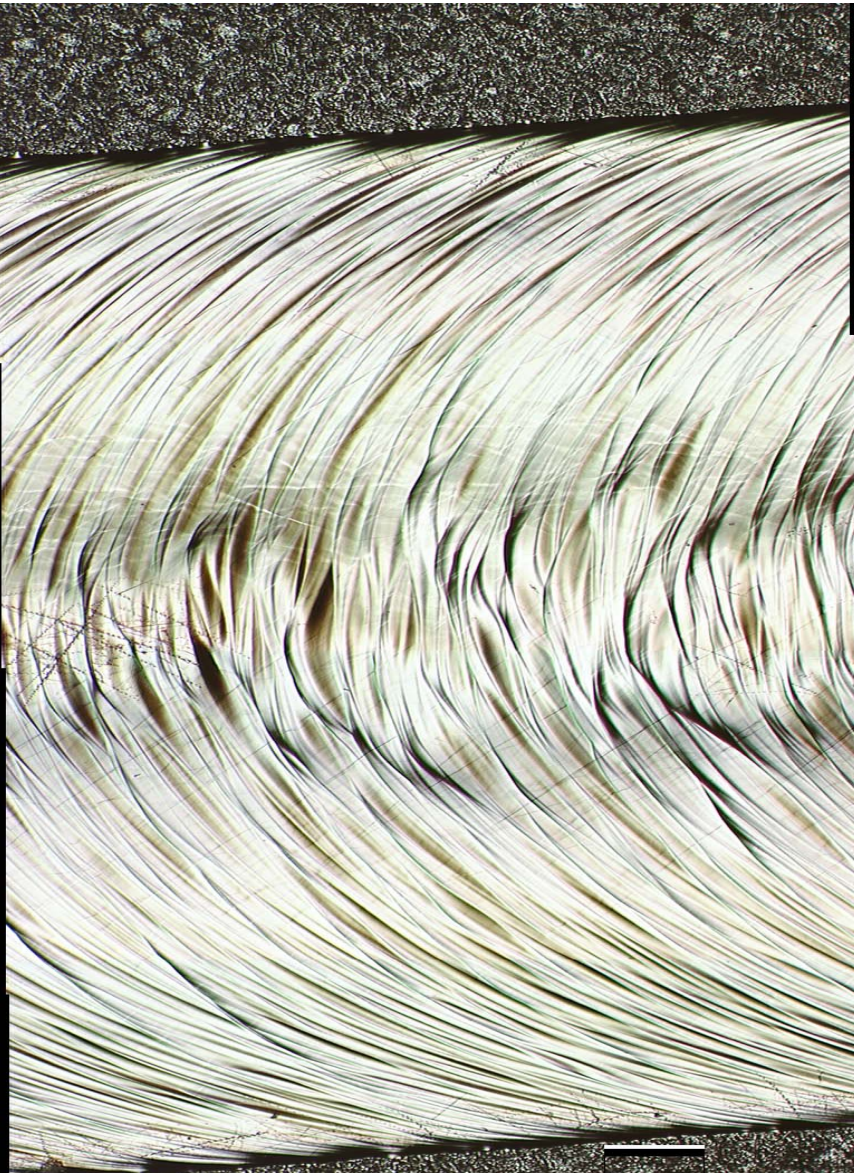
RMS: 1274 nm fine grain bcp
27 nm single crystal bcp
251 nm fine grain ep



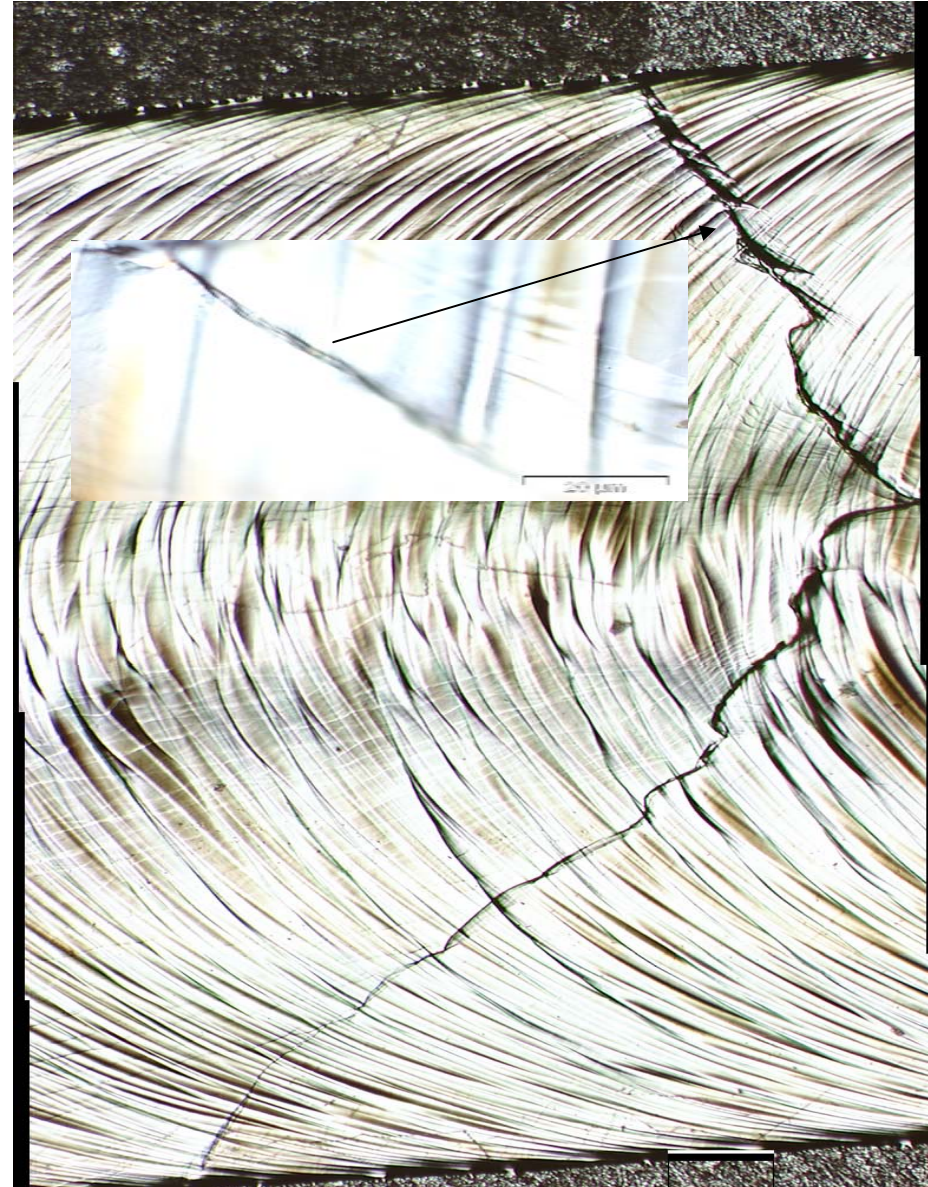
Ein großer Kristall

X. Singer

Korngrenze zwischen zwei
Kristallen



200 μm



200 μm

Single Crystal Niobium Cavity (8)

Springback in Deep Drawn High Purity Niobium for Superconductor Cavities*

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Superconducting radio frequency (SRF) cavities made from deep drawn high purity niobium have become a popular approach for the design of particle accelerators. A number of current accelerators use this technology and it is a leading candidate for future designs. The development of this technology has required significant advances in many scientific fields including metallurgy, high vacuum physics, surface science, and forming. Recently proposed modifications to the current process for fabrication of these cavities has resulted in increased concern about the distribution of deformation, residual stress patterns, and springback. This presentation will report on the findings of a recently initiated program to study plastic flow and springback in the fabrication of these cavities and the influence of metallurgical variables including grain size and impurity content.

Single Crystal Niobium Cavity (9)

Nb Discs

LL cavity 2.3GHz

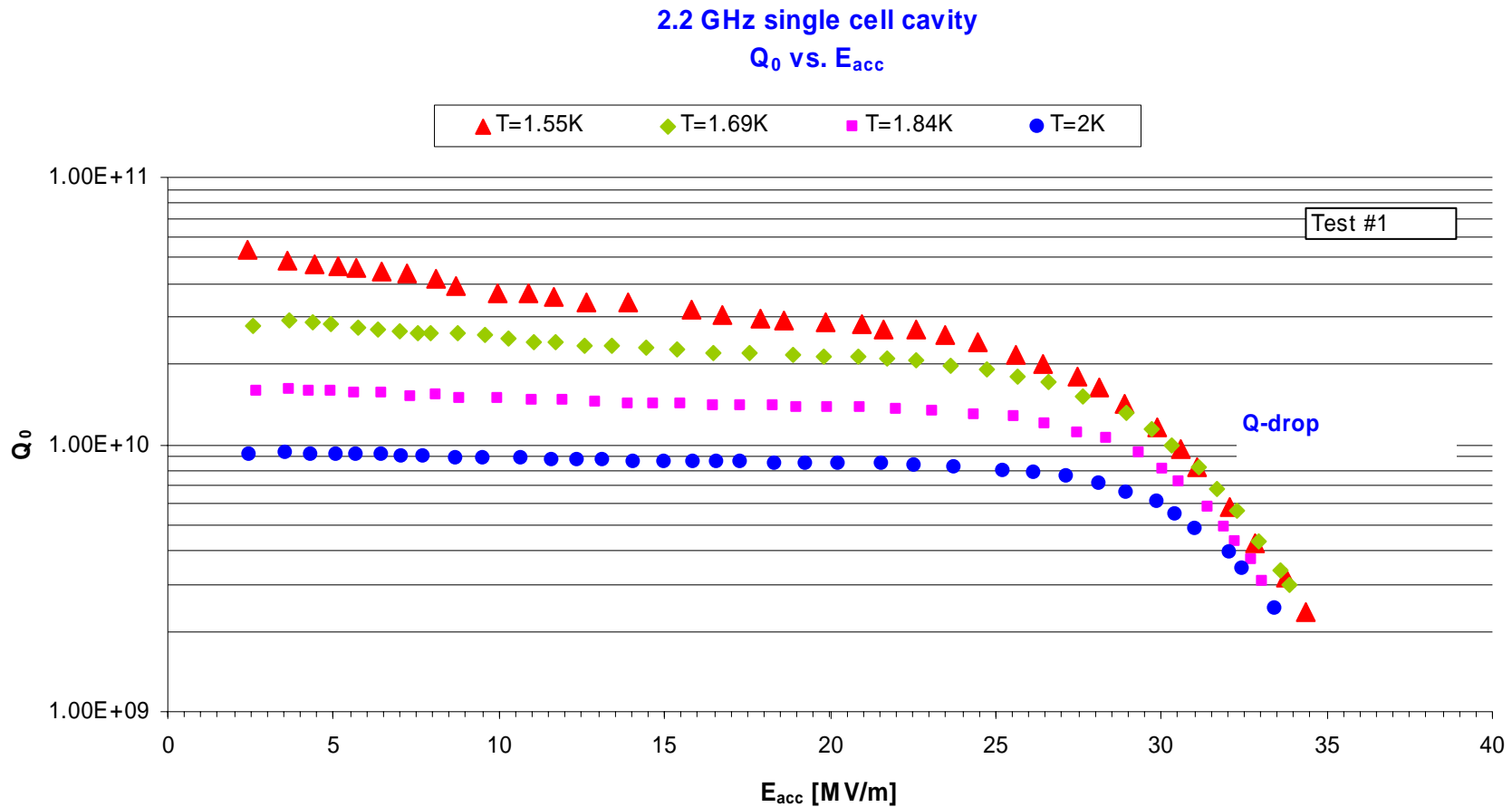
$$E_{\text{peak}}/E_{\text{acc}} = 2.072$$

$$H_{\text{peak}}/E_{\text{acc}} = 3.56 \text{ mT/MV/m}$$



Standard Material: 2.2 GHz

Test #1: ~ 100 mm bcp, 800C, 3 hrs, ~ 80 mm bcp



Single Crystal Niobium Cavity (10)

Development Program

Material	Cavity/f [MHz]	Status	Results
Single crystal	HG, 2.2 GHz	tested	$E_{acc} = 38-43 \text{ MV/m}$ $R_{res} < 1 \text{ n}\Omega$
standard	HG, 2.2 GHz	tested	$E_{acc} \sim 35 \text{ MV/m}$ $R_{res} \sim 2 \text{ n}\Omega$
Single Crystal	LL-ILC, 2.3 GHz	Fabricated, H-degassed	
Large Grain "A"	HG, 1.5 GHz	tested	$E_{acc} = 32 \text{ MV/m}$ $R_{res} \sim 7 \text{ n}\Omega$
Large Grain "B"	HG, 1.5 GHz	tested	$E_{acc} = 30 \text{ MV/m}$ $R_{res} \sim 7 \text{ n}\Omega$
Large Grain "A"	7-cell, HG, 1.5 GHz	In fabrication	
Single Crystal	7-cell, LL_ILC 1.3 GHz	Dies in fab Ingot in proc	
Large Grain "A"	HG, 1.5 GHz OC, 1.5 GHz	In fab, Saw cut	

Single Crystal Niobium Cavity (11)

What are the potential advantages of large grain/single crystal niobium?

- Reduced costs
- Comparable performance
- Very smooth surfaces with BCP
- Possibly elimination of "in situ" baking because of "Q-drop" onset at higher gradients
- Possibly very low residual resistances (high Q's), favoring lower operation temperature (B.Petersen)
- Good or better mechanical performance than fine grain material (e.g. predictable spring back..)